

## TRANSMITTAL

Electronic Version v1.1

Stylesheet Version v1.1.0

### Title of Invention

LOW VOLTAGE ELECTRON SOURCE WITH SELF ALIGNED GATE  
APERTURES, FABRICATION METHOD THEREOF, AND LUMINOUS  
DISPLAY USING THE ELECTRON SOURCE

Application Number :

Date :

First Named Applicant: Zhidan Li Tolt

Confirmation Number:

Attorney Docket Number: nanogate120303

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Submitted By:	Elec. Sign.	Sign. Capacity
Zhidan Li Tolt	/Zhidan Tolt	Inventor

Documents being submitted:	Files
us-declaration	nanogate-usdecl.xml us-declaration.dtd us-declaration.xsl
us-fee-sheet	nanogate-usfees.xml us-fee-sheet.xsl us-fee-sheet.dtd
us-ids	nanogate-usidst.xml us-ids.dtd us-ids.xsl
us-request	nanogate-usrequ.xml us-request.dtd us-request.xsl
application-body	SPECIFICATION-trans.xml us-application-body.xsl application-body.dtd wipo.ent mathml2.dtd mathml2-qname-1.mod isoamsa.ent isoamsb.ent isoamsc.ent isoamsn.ent isoamso.ent isoamsr.ent isogr3.ent isomfrk.ent isomopf.ent isomscr.ent isotech.ent isobox.ent isocyr1.ent isocyr2.ent isodia.ent isolat1.ent isolat2.ent isonum.ent isopub.ent mmlextra.ent mmlalias.ent soextblx.dtd nanogatefig1.tif nanogatefig2.tif nanogatefig3.tif nanogatefig4.tif nanogatefig5.tif nanogatefig6.tif nanogatefig7.tif nanogatefig8.tif nanogatefig9.tif

Comments

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